



# **ISD1100 SERIES**

**SINGLE-CHIP,  
VOICE RECORD / PLAYBACK DEVICES  
10- AND 12-SECOND DURATION**

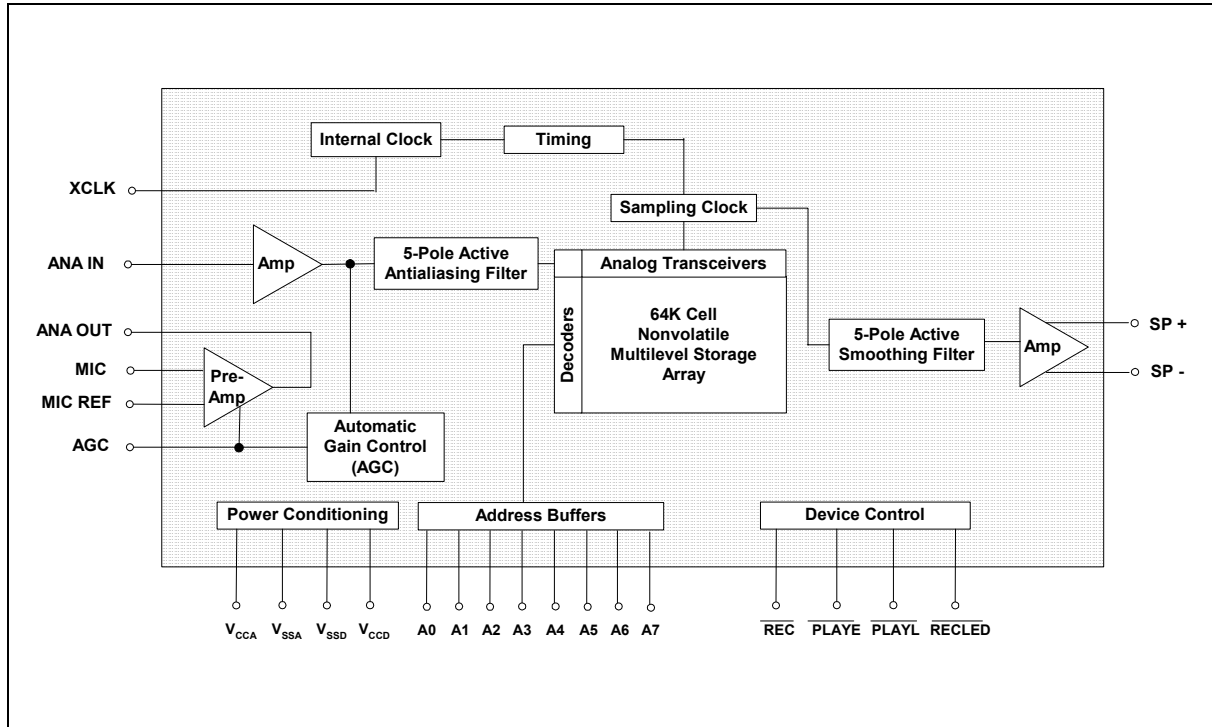
## 1. GENERAL DESCRIPTION

Winbond's ChipCorder® ISD1100 series provide high-quality, single-chip, Record/Playback solutions to 10- and 12-second messaging applications. The CMOS devices include an on-chip oscillator, microphone preamplifier, automatic gain control, anti-aliasing filter, smoothing filter, and speaker amplifier. A minimum Record/Playback subsystem can be configured with a microphone, a speaker, several passive components, two push buttons and a power source. Recordings are stored into on-chip nonvolatile memory cells, providing zero-power message storage. This unique, single-chip solution is made possible through Winbond's patented Multi-Level Storage (MLS) technology. Voice and audio signals are stored directly into memory in their natural form, providing high-quality, solid-state voice reproduction.

## 2. FEATURES

- Single 5 volt power supply
- Single-Chip with 10 and 12 seconds duration
- Easy-to-use single-chip, voice record/playback solution
- Push-button interface
  - Playback can be edge- or level-activated
- Fully addressable to handle multiple messages
- Automatic power-down
  - Enters into standby mode automatically following a record or playback operation
  - 0.5  $\mu$ A Standby current (typical)
- Zero-power message storage
  - Eliminates battery backup circuits
- High-quality, natural voice/audio reproduction
- On-chip oscillator
- No programmer or development system needed
- 100,000 record cycles (typical)
- 100-year message retention (typical)
- Available in die, PDIP, and SOIC
- Temperature: Commercial - Packaged unit : 0°C to 70°C, Die : 0°C to 50°C

## 3. BLOCK DIAGRAM

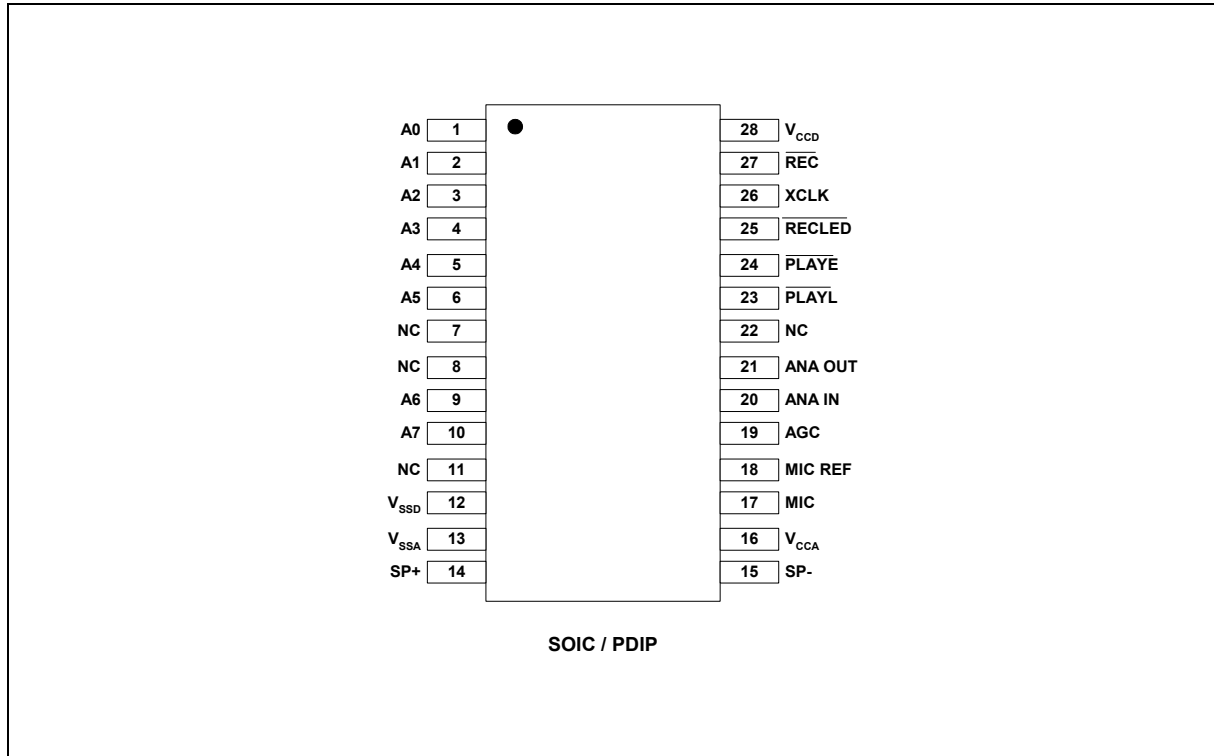




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## 5. PIN CONFIGURATION



## 6. PIN DESCRIPTION

PIN NAME	PIN NO.	FUNCTION
A0-A7	1-6, 9, 10	<p><b>Address Inputs:</b> The address inputs have two functions, depending on the level of the two Most Significant Bits (MSB) of the address (A6 and A7).</p> <p>If either or both of the two MSBs are LOW, all inputs are interpreted as address bits and are used as the start address for the current record or playback cycle. The address pins are inputs only and do not output internal address information as the operation progresses. Address inputs are latched by the falling edge of <math>\overline{\text{PLAYE}}</math>, <math>\overline{\text{PLAYL}}</math>, or <math>\overline{\text{REC}}</math>.</p> <p>If both A6 &amp; A7 are HIGH, then the device is in a special operational mode for looping. Please refer to looping capability section for details.</p> <p>A0, A1, A2, A3, A4 and A5 have internal pull-down resistors, while A6 and A7 have internal pull-up resistors. They can be floating if not used. Each of these internal pull-up or pull-down devices have a value of 50 K <math>\Omega</math> to 100 K <math>\Omega</math>.</p>
$V_{\text{SSA}}$ , $V_{\text{SSD}}$	12, 13	<p><b>Ground:</b> Similar to <math>V_{\text{CCA}}</math> and <math>V_{\text{CCD}}</math>, separate analog and digital ground rails provide independent analog and digital ground buses internally to minimize noise. These pins should be tied together as close as possible to the device.</p>
SP+, SP-	14, 15	<p><b>Speaker Outputs:</b> The differential SP+ and SP- pins are designed to drive a 16<math>\Omega</math> speaker directly. Conversely, with single-ended connection, a coupling capacitor is needed between the SP pin and the speaker. Besides, the output power is about a quarter of that from differential output. The speaker outputs are in high-impedance state during recording and at <math>V_{\text{SSA}}</math> during power down.</p>
$V_{\text{CCA}}$ , $V_{\text{CCD}}$	16, 28	<p><b>Supply Voltages:</b> Separate analog and digital powers provide power to internal analog and digital circuits respectively to minimize internal noises. These power buses are brought out to separate pads and should be tied together as close to the supply source as possible. It is important that the power supplies are decoupled as close to the device as possible.</p>
MIC	17	<p><b>Microphone:</b> The microphone input transfers its signal to the on-chip preamplifier. An on-chip Automatic Gain Control (AGC) circuit controls the gain of this preamplifier from -15 to 24dB. An external microphone should be AC coupled to this pin via a series capacitor. The capacitor value, together with the internal 10 K<math>\Omega</math> resistance on this pin, determines the low-frequency cutoff for the device passband. See Winbond's Application Information for additional information on low-frequency cutoff calculation.</p>

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PIN NAME	PIN NO.	FUNCTION
MIC REF	18	<b>Microphone Reference:</b> The MIC REF input is the inverting input to the microphone preamplifier. This provides a noise-canceling or common-mode rejection input to the device when connected to a differential microphone.
AGC	19	<b>Automatic Gain Control (AGC):</b> The AGC input dynamically adjusts the gain of the preamplifier to compensate for the wide range of microphone input levels. The AGC allows the full range of sound, from whispers to loud sounds, to be recorded with minimal distortion. The “attack” time is determined by the time constant of a 5 K $\Omega$ internal resistance and an external capacitor (C6 of Figure 5 in Section 11) connected from the AGC pin to V <sub>SSA</sub> . The “release” time is determined by the time constant of an external resistor (R5) and an external capacitor (C6) connected in parallel between the AGC pin and V <sub>SSA</sub> pin. Nominal values of 470 K $\Omega$ and 4.7 $\mu$ F give satisfactory results in most cases. Tying this to ground gives maximum gain, while tying it to V <sub>CCA</sub> gives minimum gain for the AGC amplifier.
ANA IN	20	<b>Analog Input:</b> The ANA IN transfers an input signal to the chip for recording. For microphone usage, this ANA IN pin should be connected via an external capacitor to the ANA OUT pin. This capacitor value, together with the 3 K $\Omega$ input impedance of ANA IN, is selected to give additional cutoff at the low-frequency end of the voice passband. If the desired input is derived from a source other than a microphone, the signal can be capacitively coupled into the ANA IN pin directly.
ANA OUT	21	<b>Analog Output:</b> This pin provides the preamplifier output to the user. The voltage gain of the preamplifier is determined by the voltage level at the AGC pin.
$\overline{\text{PLAYL}}$ [2][3]	23	<b>Playback, Level-Activated:</b> When this input signal is held LOW, a playback cycle is initiated, and playback continues until $\overline{\text{PLAYL}}$ is pulled HIGH, or an EOM marker is detected. The device automatically powers down and enters into standby mode upon completion of a playback cycle. This pin has an internal pull-up resistor.
$\overline{\text{PLAYE}}$ [2][3]	24	<b>Playback, Edge-Activated:</b> When a LOW-going transition is detected on this pin, a playback cycle begins. Taking $\overline{\text{PLAYE}}$ HIGH during a playback cycle will not terminate the current cycle. Playback continues until an EOM is encountered. Upon completion of a playback cycle, the device automatically powers down and enters into standby mode. This pin has an internal pull-up device.

PIN NAME	PIN NO.	FUNCTION									
RECLED	25	<p><b>Record LED:</b> The RECLED output is LOW during a record cycle. It can be used to drive an LED to indicate a record cycle is in progress. In addition, RECLED pulses LOW momentarily when an end-of-message is encountered in a playback operation.</p>									
XCLK	26	<p><b>External Clock:</b> The external clock input has an internal pull-down resistor. The ISD1100 is configured at the factory with an internal sampling clock frequency that guarantees its minimum nominal record/playback time. For instance, an ISD1110 operating within specification will be observed to always have a minimum of 10 seconds of recording time. The sampling frequency is then maintained to a variation of <math>\pm 2.25</math> percent over the commercial temperature and operating voltage ranges while still maintaining the minimum duration specified. As a result some devices will have a few percent more than nominal recording time. If greater precision is required, the device can be clocked through the XCLK pin as follows:</p> <p style="text-align: center;"><b>EXTERNAL CLOCK SAMPLE RATES</b></p> <table> <tr> <th>Part Number</th><th>Sample Rate</th><th>Required Clock</th></tr> <tr> <td>ISD1110</td><td>6.4 kHz</td><td>819.2 kHz</td></tr> <tr> <td>ISD1112</td><td>5.3 kHz</td><td>682.7 kHz</td></tr> </table> <p>These recommended clock rates should not be varied because the anti-aliasing and smoothing filters are fixed, and aliasing problems can occur if the sample rate differs from the one recommended. The duty cycle on the input clock is not critical, as the clock is immediately divided by two. <b>If the XCLK is not used, this pin must be grounded.</b> Please see Application Information for the ISD1100 series for more details on external clocking.</p>	Part Number	Sample Rate	Required Clock	ISD1110	6.4 kHz	819.2 kHz	ISD1112	5.3 kHz	682.7 kHz
Part Number	Sample Rate	Required Clock									
ISD1110	6.4 kHz	819.2 kHz									
ISD1112	5.3 kHz	682.7 kHz									

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PIN NAME	PIN NO.	FUNCTION
$\overline{\text{REC}}$ <sup>[1][3]</sup>	27	<p><b>Record:</b> The <math>\overline{\text{REC}}</math> input is an active-LOW signal. The device records whenever <math>\overline{\text{REC}}</math> is LOW. This signal must remain LOW for the duration of the recording. A record cycle is completed when <math>\overline{\text{REC}}</math> is pulled HIGH or the memory space is filled up.</p> <p><math>\overline{\text{REC}}</math> takes precedence over either playback ( <math>\overline{\text{PLAYE}}</math> or <math>\overline{\text{PLAYL}}</math> ) signal. If <math>\overline{\text{REC}}</math> is pulled LOW during a playback cycle, the playback immediately ceases and recording begins.</p> <p>An end-of-message (EOM) marker is internally recorded, enabling a subsequent playback cycle to terminate appropriately. The device automatically powers down into standby mode when <math>\overline{\text{REC}}</math> goes HIGH. This pin has an internal pull-up resistor.</p>
NC	11	<b>NC:</b> No connect

## Notes:

- <sup>[1]</sup> The  $\overline{\text{REC}}$  signal is debounced for 50 ms on the rising edge to prevent a false retriggering from a push-button switch.
- <sup>[2]</sup> During playback, if either  $\overline{\text{PLAYE}}$  or  $\overline{\text{PLAYL}}$  is held LOW during EOM or OVF, the device will still enter into standby mode and the internal oscillator and timing generator will stop. However, the rising edge of  $\overline{\text{PLAYE}}$  and  $\overline{\text{PLAYL}}$  are not debounced and any subsequent falling edge (particularly switch bounce) present on the input pins will initiate another playback.
- <sup>[3]</sup>  $\overline{\text{REC}}$ ,  $\overline{\text{PLAYL}}$  and  $\overline{\text{PLAYE}}$  have internal pull-ups to  $V_{CC}$ . Holding on these pins LOW will increase standby current consumption.



## 7. FUNCTIONAL DESCRIPTION

### 7.1. DETAILED DESCRIPTION

#### Speech/Sound Quality

Winbond's patented ChipCorder® technology provides natural audio record and playback. The ISD1100 series include devices of 5.3 kHz and 6.4 kHz sampling frequencies, allowing the user a choice of speech quality options. The input voice signals are stored directly into non-volatile EEPROM cells and are reproduced without the synthetic effect often heard with digital solid-state speech solutions. A complete sample is stored in a single cell, minimizing the memory necessary to store a recording of a given duration.

#### Duration

The ISD1100 series offer single-chip solutions of 10 and 12 seconds duration.

**TABLE 1: ISD1100 SERIES PRODUCT SUMMARY**

Part Number	Duration (Seconds)	Input Sample Rate (kHz)	Typical Filter Pass Band* (kHz)
ISD1110	10	6.4	2.6
ISD1112	12	5.3	2.2

\* 3dB roll-off-point....

#### EEPROM Storage

One of the benefits of Winbond's ChipCorder® technology is the use of on-chip non-volatile memory, providing zero-power message storage. The message is retained for up to 100 years typically without power. In addition, the device can be re-recorded typically over 100,000 times.

#### Basic Operation

The ISD1100 ChipCorder® series are controlled by a single signal,  $\overline{\text{REC}}$ , or one of two playback control signals,  $\overline{\text{PLAYE}}$  (edge-activated playback), and  $\overline{\text{PLAYL}}$  (level-activated playback). The ISD1100 series parts are configured for simplicity of design in a single/multiple-message application. Using the address lines will allow multiple message applications.

#### Automatic Power-Down Mode

At the end of a playback or record operation, the ISD1100 series automatically enters into a standby mode, with typically 0.5  $\mu\text{A}$  current. During a playback cycle, the device powers down automatically at the end of the message. During a record cycle, the device powers down immediately after  $\overline{\text{REC}}$  is released HIGH.

## Addressing

In addition to single-message application, the ISD1100 series provides a full addressing capability for multiple message application.

The memory array of ISD1100 series has 80 distinct addressable rows, providing the below resolutions per row. See Application Information for address tables of ISD1100 series.

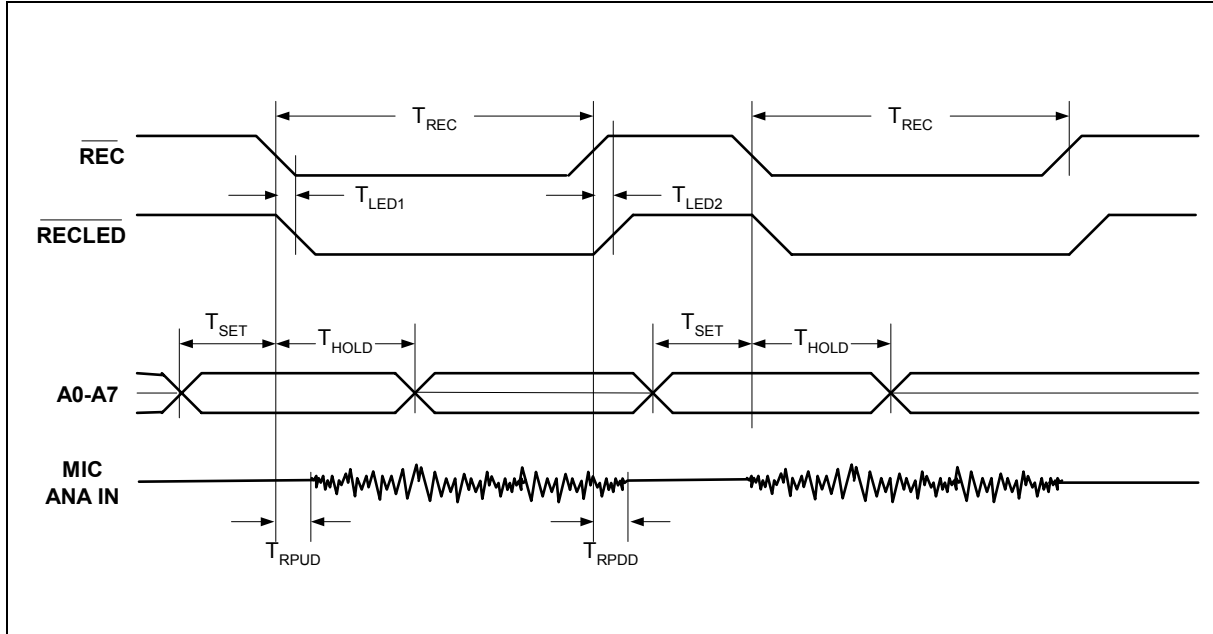
**TABLE 2: DEVICE PLAYBACK/RECORD DURATIONS**

Part Number	Minimum Duration (per ROW)
ISD1110	125 msec
ISD1112	150 msec

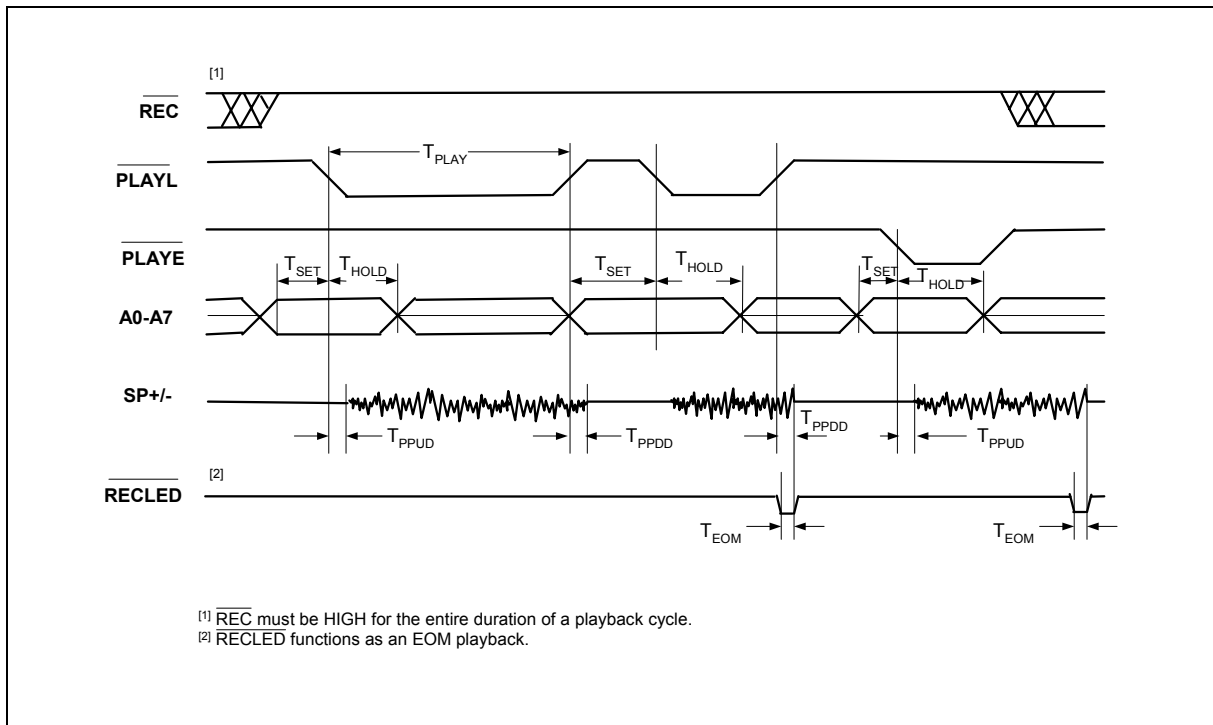
## Looping Capability

The ISD1100 series device has a built-in looping function enabling it to continuously repeat a single message. This mode is accomplished by taking A3, A6 and A7 pins HIGH simultaneously to continuously loop from the end of the message to the beginning of the message. Looping is initiated by a negative transition on PLAYE pin with A3, A6 and A7 held HIGH, then PLAYE is brought back to HIGH. Looping will continue indefinitely with all three control pins ( PLAYE , PLAYL , REC ) remaining HIGH, until PLAYL is pulsed to LOW, which ends the looping.

## 8. TIMING DIAGRAMS



**FIGURE 1: RECORD**



**FIGURE 2: PLAYBACK**

## 9. ABSOLUTE MAXIMUM RATINGS <sup>[1]</sup>

**TABLE 3: ABSOLUTE MAXIMUM RATINGS (PACKAGED PARTS)**

CONDITIONS	VALUES
Junction temperature	150°C
Storage temperature range	-65°C to +150°C
Voltage applied to any pin	(V <sub>SS</sub> – 0.3V) to (V <sub>CC</sub> + 0.3V)
Voltage applied to any pins (Input current limited to ±20 mA)	(V <sub>SS</sub> – 1.0V) to (V <sub>CC</sub> + 1.0V)
Lead temperature (Soldering – 10sec)	300°C
V <sub>CC</sub> – V <sub>SS</sub>	-0.3V to +7V

**TABLE 4: ABSOLUTE MAXIMUM RATINGS (DIE)**

CONDITIONS	VALUES
Junction temperature	150°C
Storage temperature range	-65°C to +150°C
Voltage applied to any pad	(V <sub>SS</sub> – 0.3V) to (V <sub>CC</sub> + 0.3V)
Voltage applied to any pad (Input current limited to ±20mA)	(V <sub>SS</sub> – 1.0V) to (V <sub>CC</sub> + 1.0V)
V <sub>CC</sub> – V <sub>SS</sub>	-0.3V to +7V

<sup>[1]</sup> Stresses above those listed may cause permanent damage to the device. Exposure to the absolute maximum ratings may affect device reliability and performance. Functional operation is not implied at these conditions.

## 9.1 OPERATING CONDITIONS

**TABLE 5: OPERATING CONDITIONS (PACKAGED PARTS)**

CONDITIONS	VALUES
Commercial operating temperature range (Case temperature)	0°C to +70°C
Supply voltage ( $V_{CC}$ ) <sup>[1]</sup>	+4.5V to +5.5V
Ground voltage ( $V_{SS}$ ) <sup>[2]</sup>	0V

**TABLE 6: OPERATING CONDITIONS (DIE)**

CONDITIONS	VALUES
Commercial operating temperature range	0°C to +50°C
Supply voltage ( $V_{CC}$ ) <sup>[1]</sup>	+4.5V to +6.5V
Ground voltage ( $V_{SS}$ ) <sup>[2]</sup>	0V

<sup>[1]</sup>  $V_{CC} = V_{CCA} = V_{CCD}$

<sup>[2]</sup>  $V_{SS} = V_{SSA} = V_{SSD}$

## 10. ELECTRICAL CHARACTERISTICS

### 10.1. PARAMETERS FOR PACKAGED PARTS

TABLE 7: DC PARAMETERS

PARAMETERS	SYMBOLS	MIN <sup>[2]</sup>	TYP <sup>[1]</sup>	MAX <sup>[2]</sup>	UNITS	CONDITIONS
Input Low Voltage	V <sub>IL</sub>			0.8	V	
Input High Voltage	V <sub>IH</sub>	2.4			V	
Output Low Voltage	V <sub>OL</sub>			0.4	V	I <sub>OL</sub> = 4.0 mA
Output High Voltage	V <sub>OH</sub>	2.4			V	I <sub>OH</sub> = -1.6 $\mu$ A
V <sub>CC</sub> Current (Operating)	I <sub>CC</sub>		15	30	mA	V <sub>CC</sub> = 5.5V <sup>[3]</sup> , R <sub>EXT</sub> = $\infty$
V <sub>CC</sub> Current (Standby)	I <sub>SB</sub>		0.5	2	$\mu$ A	<sup>[3]</sup> <sup>[4]</sup>
Input Leakage Current	I <sub>IL</sub>			$\pm 1$	$\mu$ A	
Input Current LOW w/ Pull Up	I <sub>ILPU</sub>			-130	$\mu$ A	Force V <sub>SS</sub> <sup>[5]</sup>
Input Current HIGH w/ Pull Down	I <sub>ILPD</sub>			130	$\mu$ A	Force V <sub>CC</sub> <sup>[6]</sup>
Output Load Impedance	R <sub>EXT</sub>	16			$\Omega$	Speaker Load
Preamp Input Resistance	R <sub>MIC</sub>		10		K $\Omega$	Pins 17, 18
ANA IN Input Resistance	R <sub>ANA IN</sub>		3		K $\Omega$	
Preamp Gain 1	A <sub>PRE1</sub>		24		dB	AGC = 0.0V
Preamp Gain 2	A <sub>PRE2</sub>		-45	-15	dB	AGC = 2.5V
ANA IN to SP+/- Gain	A <sub>ARP</sub>		22		dB	
AGC Output Resistance	R <sub>AGC</sub>		5		K $\Omega$	
Preamp Out Source	I <sub>PREH</sub>		-2		mA	@ V <sub>OUT</sub> = 1.0V
Preamp In Sink	I <sub>PREL</sub>		0.5		mA	@ V <sub>OUT</sub> = 2.0V

Notes:

[1] Typical values @ T<sub>A</sub> = 25° and V<sub>CC</sub> = 5.0V.

[2] All Min/Max limits are guaranteed by Winbond via electrical testing or characterization. Not all specifications are 100 percent tested.

[3] V<sub>CCA</sub> and V<sub>CCD</sub> connected together.

[4] REC, PLAYL, and PLAYE must be at V<sub>CCD</sub>.

[5] XCLK pin only.

[6] A0-A5, XCLK.

**TABLE 8: AC PARAMETERS – Packaged parts**

CHARACTERISTIC	SYMBOLS	MIN <sup>[2]</sup>	TYP <sup>[1]</sup>	MAX <sup>[2]</sup>	UNITS	CONDITIONS
Sampling Frequency ISD1110 ISD1112	$F_S$			6.4 5.3	kHz kHz	<sup>[5]</sup> <sup>[5]</sup>
Filter Pass Band ISD1110 ISD1112	$F_{CF}$		2.6 2.2		kHz kHz	3 dB Roll-Off Point <sup>[3][6]</sup> 3 dB Roll-Off Point <sup>[3][6]</sup>
Record Duration ISD1110 ISD1112	$T_{REC}$	10 12			sec sec	
Playback Duration ISD1110 ISD1112	$T_{PLAY}$	10 12			sec sec	<sup>[5]</sup> <sup>[5]</sup>
RECLED ON Delay	$T_{LED1}$		5		μsec	
RECLED OFF Delay ISD1110 ISD1112	$T_{LED2}$	40 50	48.5 58.3	100 105	msec msec	
A0-A7 Setup Time	$T_{SET}$	300			nsec	
A0-A7 Hold Time	$T_{HOLD}$	0			nsec	
Record Power-Up Delay ISD1110 ISD1112	$T_{RPUD}$		32 39		msec msec	
Record Power-Down Delay ISD1110 ISD1112	$T_{RPDD}$		32 39		msec msec	
Play Power-Up Delay ISD1110 ISD1112	$T_{PPUD}$		32 39		msec msec	
Play Power-Down Delay ISD1110 ISD1112	$T_{PPDD}$		8.1 9.7		msec msec	

**TABLE 8 (cont'd)**

CHARACTERISTIC	SYMBOL	MIN <sup>[2]</sup>	TYP <sup>[1]</sup>	MAX <sup>[2]</sup>	UNITS	CONDITIONS
EOM Pulse Width ISD1110 ISD1112	T <sub>EOM</sub>		15.625 18.75		msec msec	
Total Harmonic Distortion	THD		1		%	@ 1 kHz
Speaker Output Power	P <sub>OUT</sub>		12.2		mW	R <sub>EXT</sub> = 16 Ω
Voltage Across Speaker Pins	V <sub>OUT</sub>		1.25	2.5	mVp-p	R <sub>EXT</sub> = 600 Ω
MIC Input Voltage	V <sub>IN1</sub>			20	mV	Peak-to-Peak <sup>[4]</sup>
ANA IN Input Voltage	V <sub>IN2</sub>			50	mV	Peak-to-Peak

Notes:

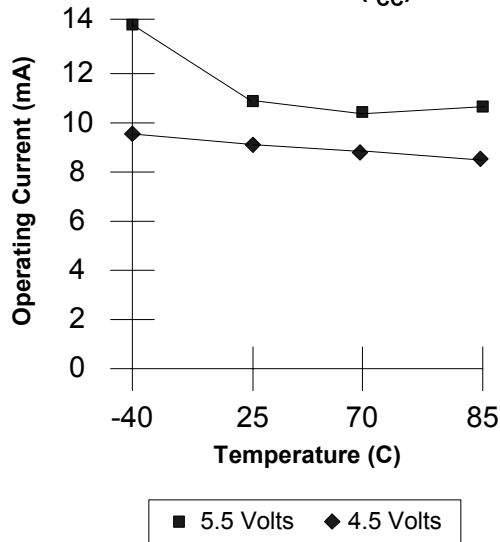
- [1] Typical values @ T<sub>A</sub> = 25° and V<sub>CC</sub> = 5.0V.
- [2] All Min/Max limits are guaranteed by Winbond via electrical testing or characterization. Not all specifications are 100 percent tested.
- [3] Low-frequency cutoff depends upon the value of external capacitors (see Pin Descriptions)
- [4] With 5.1 KΩ series resistor at ANA IN.
- [5] Sampling Frequency and playback Duration can vary as much as ±2.25 percent over the commercial temperature and voltage ranges. All devices will meet the maximum sampling frequency and minimum playback duration parameters. For greater stability, an external clock can be utilized (see Pin Descriptions)
- [6] Filter specification applies to the antialiasing filter and the smoothing filter. Typical Parameter Variation with Voltage and Temperature. This parameter is not checked during production testing and may vary due to process variations and other factors. Therefore, the customer should not rely upon this value for testing purposes.

# ISD1100 SERIES

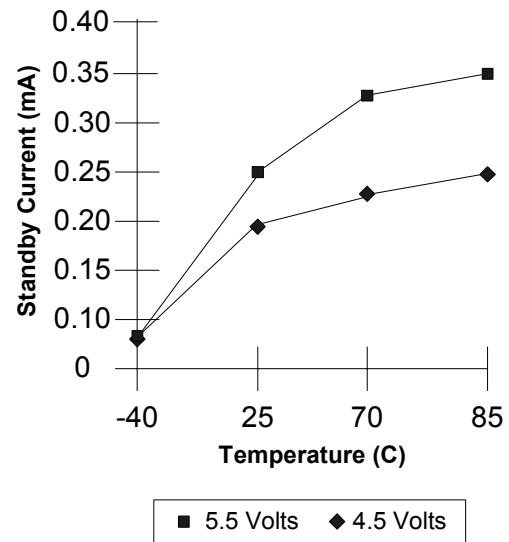


## 10.1.1. Typical Parameter Variation with Voltage and Temperature

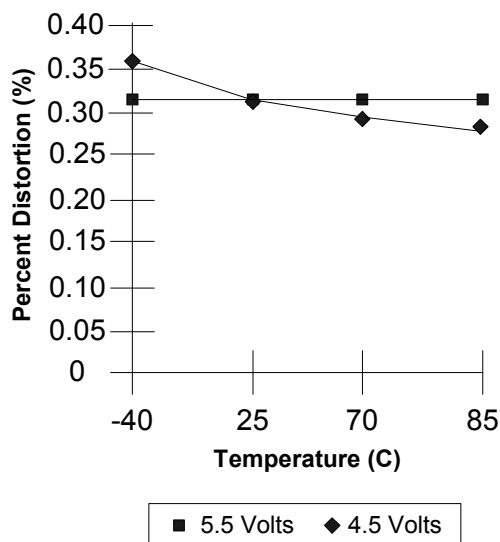
**Chart 1: Record Mode Operating Current ( $I_{CC}$ )**



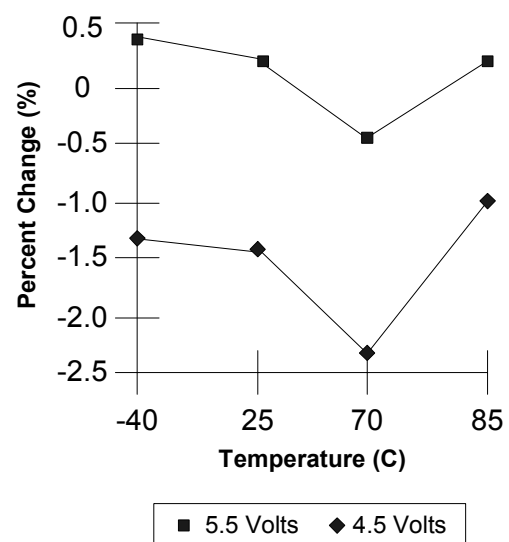
**Chart 3: Standby Current ( $I_{SB}$ )**



**Chart 2: Total Harmonic Distortion**



**Chart 4: Oscillator Stability**



## 10.2. PARAMETERS FOR DIE

**TABLE 9: DC PARAMETERS**

PARAMETERS	SYMBOLS	MIN <sup>[2]</sup>	TYP <sup>[1]</sup>	MAX <sup>[2]</sup>	UNITS	CONDITIONS
Input Low Voltage	$V_{IL}$			0.8	V	
Input High Voltage	$V_{IH}$	2.4			V	
Output Low Voltage	$V_{OL}$			0.4	V	$I_{OL} = 4.0 \text{ mA}$
Output High Voltage	$V_{OH}$	2.4			V	$I_{OH} = -1.6 \mu\text{A}$
$V_{CC}$ Current (Operating)	$I_{CC}$		15	30	mA	$V_{CC} = 5.5\text{V}^{[3]}$ , $R_{EXT} = \infty$
$V_{CC}$ Current (Standby)	$I_{SB}$		0.5	2	$\mu\text{A}$	<sup>[3]</sup> <sup>[4]</sup>
Input Leakage Current	$I_{IL}$			$\pm 1$	$\mu\text{A}$	
Input Current HIGH w/ Pull Up	$I_{ILPU}$			-130	$\mu\text{A}$	Force $V_{CC}^{[5]}$
Input Current HIGH w/ Pull Down	$I_{ILPD}$			130	$\mu\text{A}$	Force $V_{CC}^{[6]}$
Output Load Impedance	$R_{EXT}$	16			$\Omega$	Speaker Load
Preamp Input Resistance	$R_{MIC}$		10		K $\Omega$	Pads 17,18
ANA IN Input Resistance	$R_{ANA IN}$		3		K $\Omega$	
Preamp Gain 1	$A_{PRE1}$		24		dB	AGC = 0.0V
Preamp Gain 2	$A_{PRE2}$		-45	-15	dB	AGC = 2.5V
ANA IN to SP+/- Gain	$A_{ARP}$		22		dB	
AGC Output Resistance	$R_{AGC}$		5		K $\Omega$	
Preamp Out Source	$I_{PREH}$		-2		mA	@ $V_{OUT} = 1.0\text{V}$
Preamp In Sink	$I_{PREL}$		0.5		mA	@ $V_{OUT} = 2.0\text{V}$

**Notes:**

[1] Typical values @  $T_A = 25^\circ$  and  $V_{CC} = 5.0\text{V}$ .

[2] All Min/Max limits are guaranteed by Winbond via electrical testing or characterization. Not all specifications are 100 percent tested.

[3]  $V_{CCA}$  and  $V_{CCD}$  connected together.

[4] REC, PLAYL, and PLAYE must be at  $V_{CCD}$ .

[5] XCLK pin only.

[6] A0-A5, XCLK.

**TABLE 10: AC PARAMETERS**

CHARACTERISTIC	SYMBOL	MIN <sup>[2]</sup>	TYP <sup>[1]</sup>	MAX <sup>[2]</sup>	UNITS	CONDITIONS
Sampling Frequency ISD1110 ISD1112	$F_S$			6.4 5.3	kHz kHz	<sup>[5]</sup> <sup>[5]</sup>
Filter Pass Band ISD1110 ISD1112	$F_{CF}$		2.6 2.2		kHz kHz	3 dB Roll-Off Point <sup>[3][6]</sup> 3 dB Roll-Off Point <sup>[3][6]</sup>
Record Duration ISD1110 ISD1112	$T_{REC}$	10 12			sec sec	
Playback Duration ISD1110 ISD1112	$T_{PLAY}$	10 12			sec sec	<sup>[5]</sup> <sup>[5]</sup>
$\overline{RECLED}$ ON Delay	$T_{LED1}$		5		$\mu$ sec	
$\overline{RECLED}$ OFF Delay ISD1110 ISD1112	$T_{LED2}$	40 50	48.5 58.3	100 105	msec msec	
Address Setup Time	$T_{SET}$	300			nsec	
Address Hold Time	$T_{HOLD}$	0			nsec	
Power-Up Delay ISD1110 ISD1112	$T_{RPUD}$		32 39		msec msec	
PD Pulse Width (Record) ISD1110 ISD1112	$T_{RPDD}$		32 39		msec msec	
Play Power-Up Delay ISD1110 ISD1112	$T_{PPUD}$		32 39		msec msec	
Play Power-Down Delay ISD1110 ISD1112	$T_{PPDD}$		8.1 9.7		msec msec	

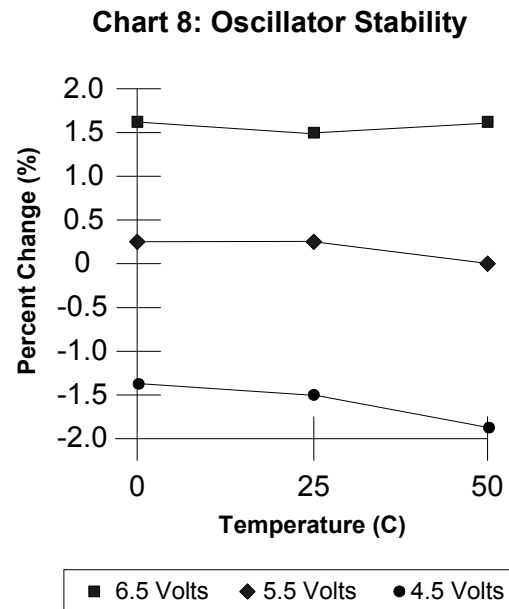
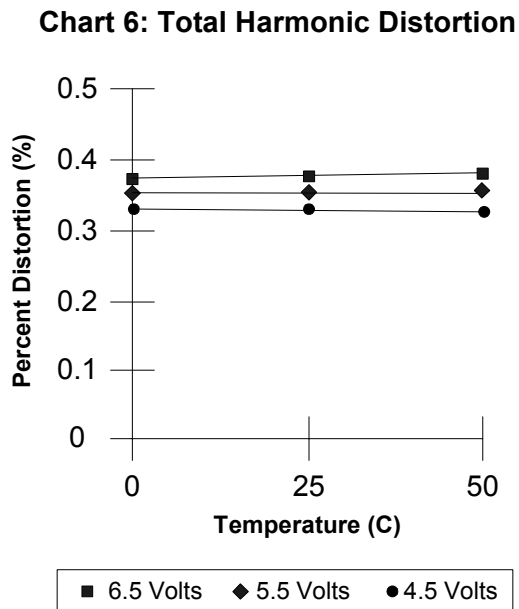
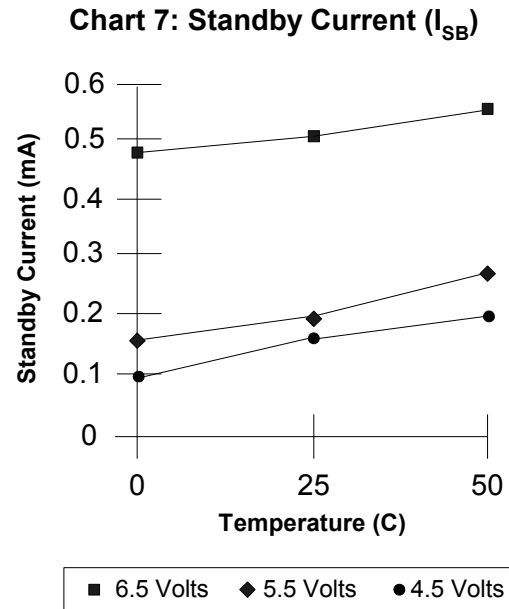
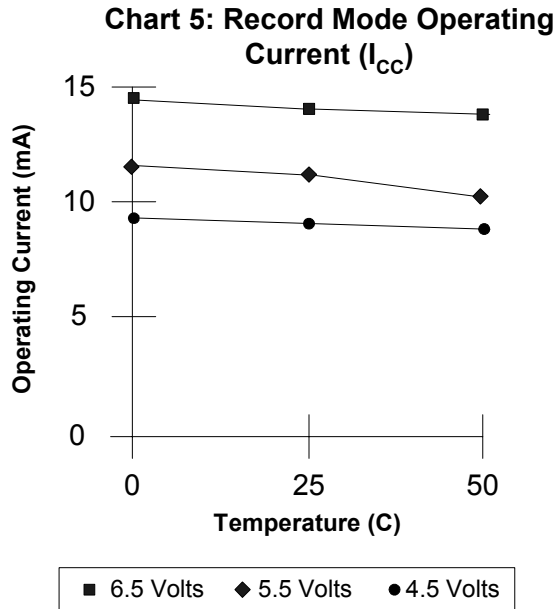
**TABLE 10 (cont'd)**

CHARACTERISTIC	SYMBOL	MIN <sup>[2]</sup>	TYP <sup>[1]</sup>	MAX <sup>[2]</sup>	UNITS	CONDITIONS
EOM Pulse Width ISD1110 ISD1112	T <sub>EOM</sub>		16.625 18.75		msec msec	
Total Harmonic Distortion	THD		1		%	@ 1 kHz
Speaker Output Power	P <sub>OUT</sub>		12.2		mW	R <sub>EXT</sub> = 16 Ω <sup>[4]</sup>
Voltage Across Speaker Pins	V <sub>OUT</sub>		1.25	2.5	mVp-p	R <sub>EXT</sub> = 600 Ω
MIC Input Voltage	V <sub>IN1</sub>			20	mV	Peak-to-Peak <sup>[4]</sup>
ANA IN Input Voltage	V <sub>IN2</sub>			50	mV	Peak-to-Peak

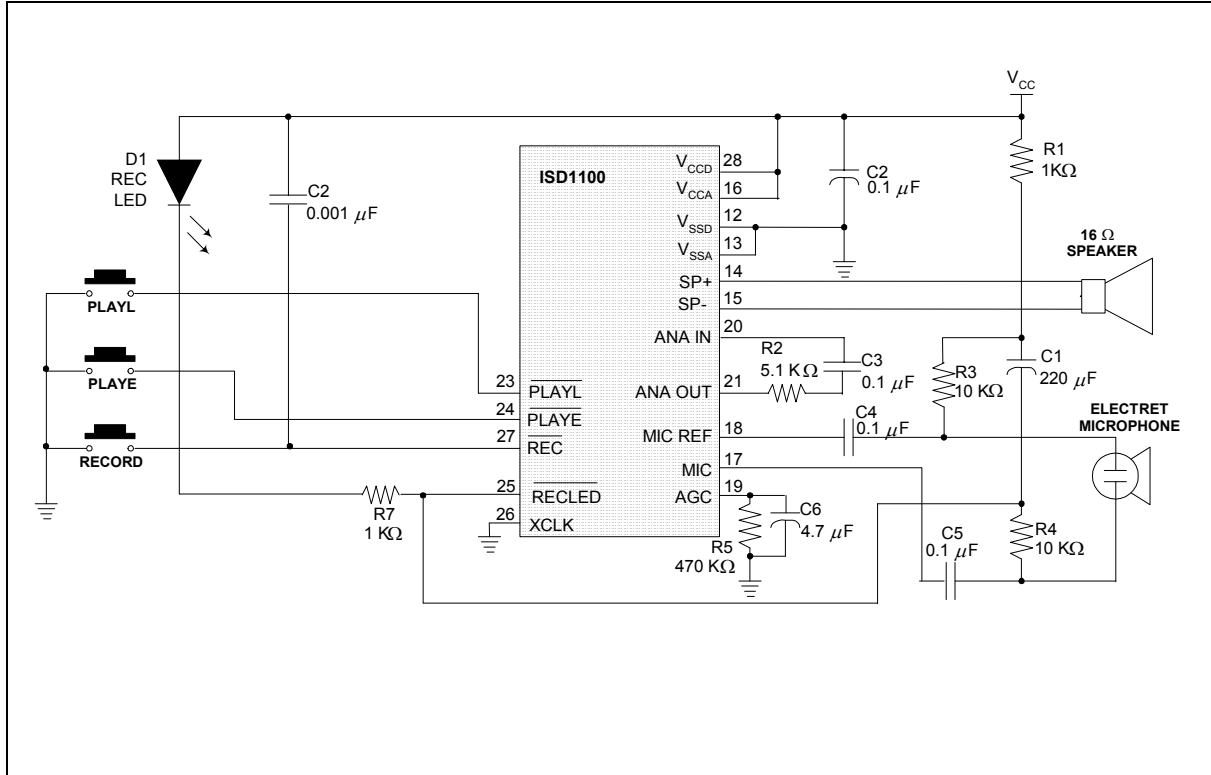
Notes:

- [1] Typical values @ T<sub>A</sub> = 25° and V<sub>CC</sub> = 5.0V.
- [2] All Min/Max limits are guaranteed by Winbond via electrical testing or characterization. Not all specifications are 100 percent tested.
- [3] Low-frequency cutoff depends upon the value of external capacitors (see Pin Descriptions)
- [4] With 5.1 KΩ series resistor at ANA IN.
- [5] Sampling Frequency and playback Duration can vary as much as ±2.25 percent over the commercial temperature and voltage ranges. All devices will meet the maximum sampling frequency and minimum playback duration parameters. For greater stability, an external clock can be utilized (see Pin Descriptions)
- [6] Filter specification applies to the antialiasing filter and the smoothing filter. Typical Parameter Variation with Voltage and Temperature. This parameter is not checked during production testing and may vary due to process variations and other factors. Therefore, the customer should not rely upon this value for testing purposes.

## 10.2.1. Typical Parameter Variation with Voltage and Temperature



## 11. TYPICAL APPLICATION CIRCUIT



**FIGURE 5: APPLICATION EXAMPLE**



## Functional Description Example

The following operating sequence example demonstrates the functionality of the ISD1100 series.

1. Record a message:

Pulling the  $\overline{\text{REC}}$  signal LOW initiates a record cycle from current location. When  $\overline{\text{REC}}$  is held LOW, the recording continues. Until the memory array is filled up or when  $\overline{\text{REC}}$  is pulled HIGH, recording ceases. An EOM marker is written at the end of message. Then the device will automatically power down.

2. Edge-activated playback:

Pulling the  $\overline{\text{PLAYE}}$  signal LOW initiates a playback cycle from the beginning of the message until the entire message is played. The rising edge of  $\overline{\text{PLAYE}}$  has no effect on operation. When the EOM marker is encountered, the device automatically powers down. A subsequent falling edge on  $\overline{\text{PLAYE}}$  initiates a new playback operation from the beginning of the message.

3. Level-activated playback:

Holding the  $\overline{\text{PLAYL}}$  signal LOW initiates a playback cycle from the beginning of the message, until  $\overline{\text{PLAYL}}$  is pulled HIGH or when the EOM marker is encountered, playback operation stops and the device automatically powers down.

4. Record (interrupting playback).

The  $\overline{\text{REC}}$  signal takes precedence over playback operation. Holding  $\overline{\text{REC}}$  LOW initiates a new record operation from current location, regardless of any current operation in progress.

5.  $\overline{\text{RECLED}}$  operation.

During record, the  $\overline{\text{RECLED}}$  output pin provides an active-LOW signal, which can be used to drive an LED as a "record-in-progress" indicator. It returns to a HIGH state when the  $\overline{\text{REC}}$  pin is pulled HIGH or when the recording is completed due to the memory being filled. However, during playback, this pin also pulses LOW to indicate an EOM at the end of a message.

## Applications Note

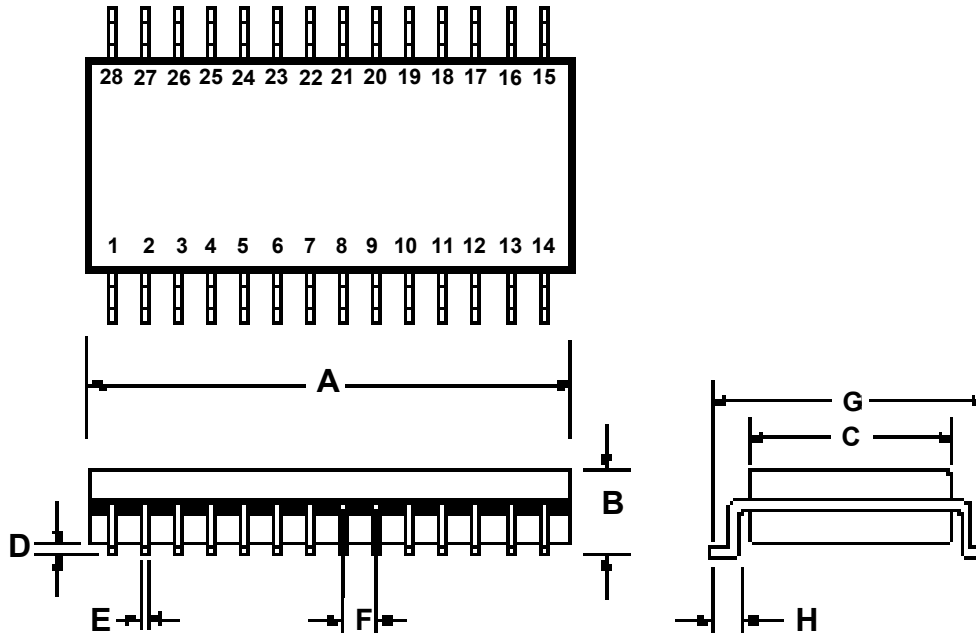
Some users may experience an unexpected recording taking place when their circuit is powered up, or the batteries are changed, and  $V_{CC}$  rises faster than  $\overline{REC}$ . This undesired recording prevents playback of the previously recorded message. A spurious EOM marker appears at the very beginning of the memory, preventing access to the original message, and nothing is played.

To prevent this occurrence, install a capacitor (approx. 0.001  $\mu F$ ) between the  $\overline{REC}$  and  $V_{CC}$  pins. This pulls the control pin voltage up with  $V_{CC}$  as it rises. Once the voltage is HIGH, the pull-up device will keep the pin HIGH until intentionally pulled LOW, preventing the false EOM marker.

Since this condition is dependent upon factors such as the capacitance of the user's printed circuit board, not all circuit designs will exhibit the spurious marker. It is recommended, however, that the capacitor is included for design reliability. A more detailed explanation and resolution of this occurrence is described in Application Information.

## 12. PACKAGE DRAWING AND DIMENSIONS

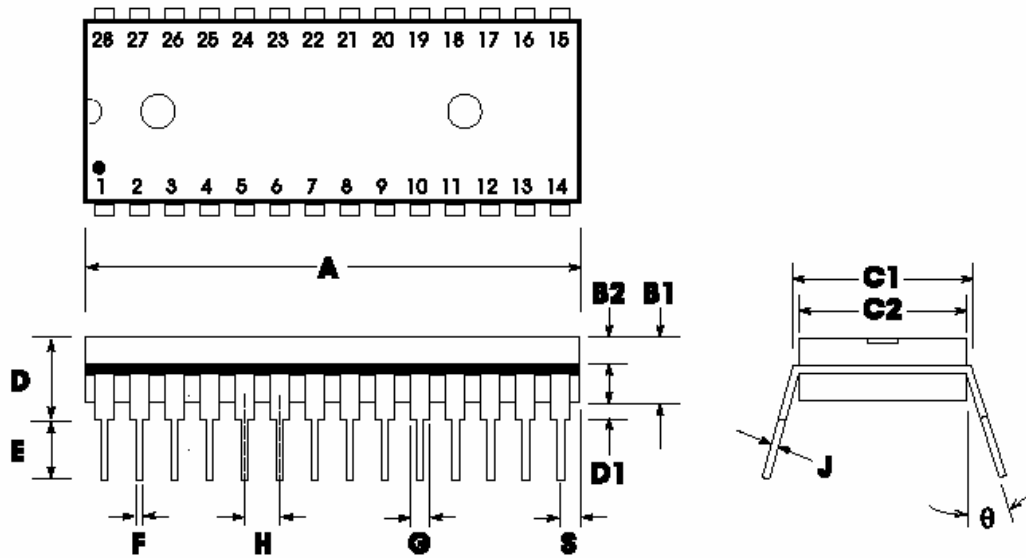
### 12.1. 28-LEAD 300MIL PLASTIC SMALL OUTLINE IC (SOIC)



	INCHES			MILLIMETERS		
	Min	Nom	Max	Min	Nom	Max
A	0.701	0.706	0.711	17.81	17.93	18.06
B	0.097	0.101	0.104	2.46	2.56	2.64
C	0.292	0.296	0.299	7.42	7.52	7.59
D	0.005	0.009	0.0115	0.127	0.22	0.29
E	0.014	0.016	0.019	0.35	0.41	0.48
F		0.050			1.27	
G	0.400	0.406	0.410	10.16	10.31	10.41
H	0.024	0.032	0.040	0.61	0.81	1.02

Note: Lead coplanarity to be within 0.004 inch.

## 12.2. 28-LEAD 600MIL PLASTIC DUAL INLINE PACKAGE (PDIP)



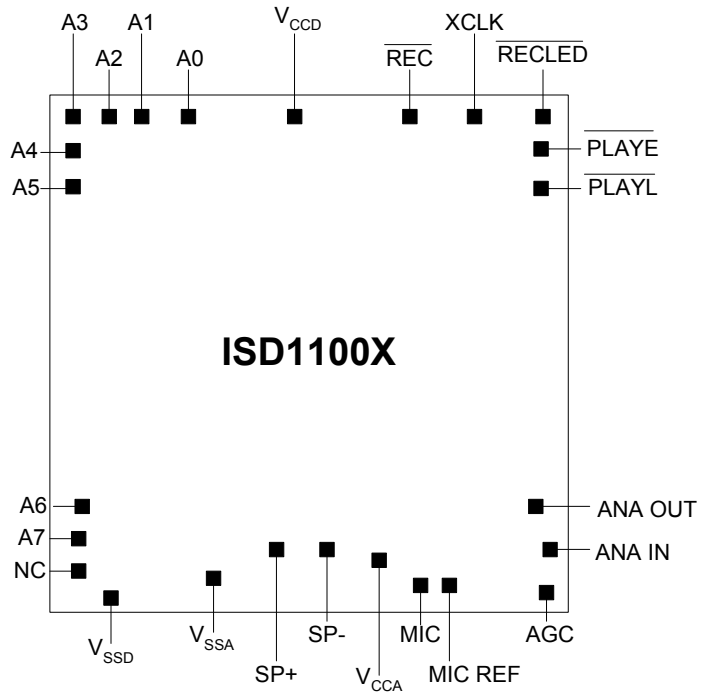
	INCHES			MILLIMETERS		
	Min	Nom	Max	Min	Nom	Max
A	1.445	1.450	1.455	36.70	36.83	36.96
B1		0.150			3.81	
B2	0.065	0.070	0.075	1.65	1.78	1.91
C1	0.600		0.625	15.24		15.88
C2	0.530	0.540	0.550	13.46	13.72	13.97
D			0.19			4.83
D1	0.015			0.38		
E	0.125		0.135	3.18		3.43
F	0.015	0.018	0.022	0.38	0.46	0.56
G	0.055	0.060	0.065	1.40	1.52	1.62
H		0.100			2.54	
J	0.008	0.010	0.012	0.20	0.25	0.30
S	0.070	0.075	0.080	1.78	1.91	2.03
q	0°		15°	0°		15°

Note: Lead coplanarity to be within 0.005 inch.

## 12.3. DIE PHYSICAL LAYOUT <sup>[1]</sup>

### ISD1100X

- Die Dimensions
  - X:  $172.2 \pm 1$  mils
  - Y:  $138.2 \pm 1$  mils
- Die Thickness <sup>[2]</sup>
  - $17.5 \pm .1$  mils
- Pad Opening
  - 88 x 112 microns
  - 3.46 x 4.41 mils



#### Notes:

- [1] The backside of die is internally connected to  $V_{SS}$ . It **MUST NOT** be connected to any other potential or damage may occur.
- [2] Die thickness is subject to change, please contact Winbond factory for status.

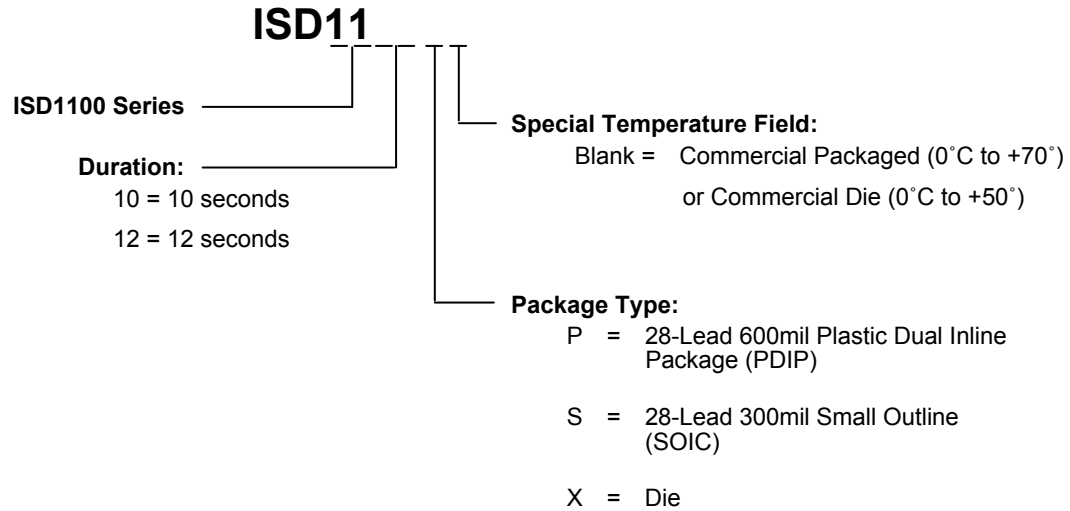
## ISD1100 SERIES PAD DESIGNATIONS

(with respect to die center)

PAD	PAD Name	X Axis ( $\mu\text{m}$ )	Y Axis ( $\mu\text{m}$ )
A0	Address 0	-1364.0	1589.6
A1	Address 1	-1648.4	1589.6
A2	Address 2	-1816.4	1589.6
A3	Address 3	-2013.6	1515.6
A4	Address 4	-2013.6	1337.6
A5	Address 5	-2013.6	1129.6
A6	Address 6	-2013.6	-831.2
A7	Address 7	-2013.6	-1022.0
NC	No Connect	-2013.6	-1361.6
V <sub>SSD</sub>	Digital Ground	-1893.6	-1588.0
V <sub>SSA</sub>	Analog Ground	-357.6	-1588.0
SP+	Speaker Output +	-17.2	-1512.8
SP-	Speaker Output -	412.4	-1512.8
V <sub>CCA</sub>	Analog Power Supply	780.0	-1552.4
MIC	Microphone Input	992.0	-1590.0
MIC REF	Microphone Reference	1169.2	-1590.0
AGC	Automatic Gain Control	1978.4	-1590.0
ANA IN	Analog Input	2005.6	-1196.4
ANA OUT	Analog Output	1991.2	-995.2
PLAYL	Level-Activated Playback	2014.4	1224.4
PLAYE	Edge-Activated Playback	2014.4	1392.8
RECLED	Record LED Output	2012.4	1587.6
XCLK	External Clock	1581.5	1589.6
REC	Record	752.8	1589.6
V <sub>CCD</sub>	Digital Power Supply	-48.0	1545.2

## 13. ORDERING INFORMATION

### Product Number Descriptor Key



When ordering ISD1100 series devices, please refer to the following valid part numbers.

Die / Package	10-Second		12-Second	
	Product P/N	Ordering P/N	Product P/N	Ordering P/N
<b>Die</b>	ISD1110X	I1110X	ISD1112X	I1112X
<b>PDIP</b>	ISD1110P	I1110P	ISD1112P	I1112P
<b>SOIC</b>	ISD1110S	I1110S	ISD1112S	I1112S

For the latest product information, access Winbond's worldwide website at <http://www.winbond-usa.com>



## 14. VERSION HISTORY

VERSION	DATE	DESCRIPTION
0	Before 2004	Initial issue
1.0	March 2004	Reformat the document. Add footnote to Filter Passband in Tables 1, 8 & 10. Revise Functional Description Example section. Revise die info. Revise ordering information.
1.1	Apr 2005	Revise the disclaim section.

# ISD1100 SERIES



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